



Cite this: *Phys. Chem. Chem. Phys.*,  
2024, 26, 635

## Correction: Structural, electronic, optical, elastic, thermodynamic and thermal transport properties of Cs<sub>2</sub>AgInCl<sub>6</sub> and Cs<sub>2</sub>AgSbCl<sub>6</sub> double perovskite semiconductors using a first-principles study

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DOI: 10.1039/d3cp90236f

rsc.li/pccp

Correction for 'Structural, electronic, optical, elastic, thermodynamic and thermal transport properties of Cs<sub>2</sub>AgInCl<sub>6</sub> and Cs<sub>2</sub>AgSbCl<sub>6</sub> double perovskite semiconductors using a first-principles study' by Keqing Zhang et al., *Phys. Chem. Chem. Phys.*, 2023, 25, 31848–31868, <https://doi.org/10.1039/d3cp03795a>.

The published version of this manuscript omitted funding information in the acknowledgements and an error in the author's information. The correct author information is shown here and the correct funding information is as follows:

This research was partially supported by the Training Program for Young Backbone Teachers of Henan Technical Institute, No. 2022-GGJS-H003, Grant-in-Aid for Scientific Research No. 21K14510 from the Japan Society for the Promotion of Science (JSPS) and the National Natural Science Foundation of China (No: 62264015 & 22175059). The authors are thankful to Asso. Prof. Raji, Department of Physics, Mepco Schlenk Engineering College, Tamil Nadu, India, for the computational facility.

The Royal Society of Chemistry apologises for these errors and any consequent inconvenience to authors and readers.

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